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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/041,896	01/07/2002	Brenda D. Kraus	MI22-1859	5572
21567 7.	590 10/07/2002			
WELLS ST. JOHN ROBERTS GREGORY & MATKIN P.S.			EXAMINER	
601 W. FIRST SUITE 1300		Brenda D. Kraus M122-1859 EGORY & MATKIN P.S. EXAMINER HUYNH, YENNI	ENNHU B	
SPOKANE, W	A 99201-3828		ART UNIT	PAPER NUMBER
			2813	
			DATE MAILED: 10/07/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)		
•	_				
Office Action Summary		10/041,896	KRAUS ET AL.		
	,	Examiner	Art Unit		
	The MAILING DATE of this communication app	Yennhu B Huynh	2813		
Period f	or Reply	Jears on the cover sheet with the	correspondence address		
THE - External control	MAILING DATE OF THIS COMMUNICATION. msions of time may be available under the provisions of 37 CFR 1.1 SIX (6) MONTHS from the mailing date of this communication. e period for reply specified above is less than thirty (30) days, a repl period for reply is specified above, the maximum statutory period one to reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be t y within the statutory minimum of thirty (30) da will apply and will expire SIX (6) MONTHS fron the cause the application to become ARANDON	imely filed ays will be considered timely. The the mailing date of this communication. FD (35.U.S.C. & 133)		
1)⊠	Responsive to communication(s) filed on 127	<u> August 2002</u> .			
2a)□	This action is FINAL . 2b)⊠ Th	is action is non-final.			
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213. Disposition of Claims					
4)⊠	Claim(s) 21-28 is/are pending in the application	n.			
	4a) Of the above claim(s) is/are withdraw	wn from consideration.			
5)	Claim(s) is/are allowed.				
6)⊠	Claim(s) 21-28 is/are rejected.				
7)	Claim(s) is/are objected to.				
8)[8) Claim(s) are subject to restriction and/or election requirement.				
Applicati	on Papers				
9)[The specification is objected to by the Examine	r.			
10) 🔲	The drawing(s) filed on is/are: a)☐ accep	oted or b) objected to by the Exa	aminer.		
	Applicant may not request that any objection to the	e drawing(s) be held in abeyance. S	See 37 CFR 1.85(a).		
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.					
	If approved, corrected drawings are required in rep	•			
12) 🔲	The oath or declaration is objected to by the Ex	aminer.			
Priority (ınder 35 U.S.C. §§ 119 and 120				
13)	Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. § 119(a	a)-(d) or (f).		
a)[All b) Some * c) None of:				
	1. Certified copies of the priority documents	s have been received.			
	2. Certified copies of the priority documents have been received in Application No				
Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.					
14) 🗌 A	cknowledgment is made of a claim for domestic	priority under 35 U.S.C. § 119(e) (to a provisional application).		
a	The translation of the foreign language proacknowledgment is made of a claim for domesti	visional application has been rec	ceived.		
Attachmen	c(s)				
2) Notice 3) Inform	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449) Paper No(s) 3.	5) Notice of Informal	y (PTO-413) Paper No(s) Patent Application (PTO-152)		
S. Patent and Tr PTO-326 (Re		tion Summary	Part of Paper No. 10		

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DETAILED ACTION

Claims 1-20, 29-41 & 57-63 and 42-56 have been cancelled by Amendments filed on 4/16/02, 5/13/02 and 8/12/02.

Election/Restrictions

Applicant's election without traverse of claims 21-28 in Paper No. 9 is acknowledged.

Claim Rejections - 35 USC § 112

Claims 24-27 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Claims 24 & 26, line 2&3 and claim 27, lines 3 & 4 recite the limitation "a thickness less than or equal to 60 Angstroms". The term expression "less" is indefinite.

Claim 25, line 2 & 3 recites the limitation "a thickness less than or equal to 50 Angstroms". The term expression "less" is indefinite.

Claim 28, the line 1 recites the limitation "substantially amorphous". The term "substantially" is unclear.

Specification

The title of the invention is not descriptive. A new title is required that is clearly indicative of the invention to which the claims are directed.

The following title is suggested: DRAM Circuitry Device Comprise An Aluminum Nitride Capacitor Dielectric Region.

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Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 21-23 & 28 are rejected under 35 U.S.C. 103(a) as being unpatentable over Tsu et al. (U.S. 6,294,420B1) in view of Forbes et al. (U.S. 6,307,775B1).

Tsu et al. disclose an array of wordlines 56a - 56d forming gate of FET and an array of bit lines 60, individual FET comprising a gate (col.7 & 8, lines 63-5, col. 9, lines 12-20, figs. 4 & 5); a plurality of memory cell storage capacitors associated with the field effect transistors, individual storage capacitors comprising a first capacitor electrode 12 in electrical connection with one of a pair of source/drain regions of one of the FET and a second capacitor electrode 14, a capacitor dielectric region 16; the region received intermediate the first and second capacitor electrodes, the region comprising nitride layer 22, the other of the pair of source/drain regions of the one field effect transistor being in electrical connection with one of the bit lines 60.

However, Tsu et al. do not disclose the contact region comprising aluminum nitride or wherein the AIN is substantially amorphous and native oxide.

Forbes et al. disclose a floating gate transistor which include a memory cell 110 include a FET 200 and the use of amorphous AlN, and an oxide for forming capacitor dielectric region (col.12, lines 45-57)

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It would have been obvious to one having ordinary skill in the art at the time the invention was made to combine the teaching from Forbes et al.'s process in using the amorphous AIN material for the dielectric region to reduce carbon and oxygen incorporation, into Tsu et al.'s process. This modification would complete the DRAM circuitry as claimed invention.

With respect to claims 24-27, Tsu et al. do not disclose that the contacts each of the first and second electrode has a thickness less than or equal to 50 or 60 angstroms.

It would have been obvious to a person of ordinary skill in the art at the time the invention was made to optimize and select an appropriate thickness for the deposition. The selection of reaction parameters such as temperature, time, depth, thickness and concentration would have been obvious and involve routine optimization which has been held to be within the level of ordinary skill in the art.

"Normally, it is to expected that a change in temperature, or in range, concentration, cycles, thickness, would be an unpatentable modification. Under some circumstance, however, changes such as these may be impart patentability to a process if the particular ranges claimed produce a new and unexpected result which is different in kind and not merely degree from the results of the prior art ... such ranges are termed "critical ranges and the applicant has the burden of proving such criticality ... More particularly, where the general conditions of a claim are disclosed in the prior art, it is not inventive to discover the optimum or workable ranges by routine experimentation."

In re Aller 105 USPQ233, 255 (CCPA 1955). See also In re Waite 77 USPQ 586 (CCPA 1948); In re Scherl 70 USPQ 204 (CCPA 1946); In re Irmscher 66 USPQ 314 (CCPA

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1945); In re Norman 66 USPQ 308 USPQ 308 (CCPA 1945); In re Swenson 56 USPQ

372 (CPA 1942); In re Sola 25 USPQ 433 (CCPA 1935); In re Dreyfus 24 USPQ 52

(CCPA 1934)

Conclusion

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Yennhu Huynh whose telephone number is

(703)308-6110. The examiner can normally be reached on Monday-Friday from

8:00 AM to 4.30PM.

If attempts to reach the examiner by telephone are unsuccessfully, the

examiner's supervisor, Olik Chaudhuri, can be reached on (703) 306-2749. The

fax phone number for the organization where this application or proceeding is

assigned is (703) 308-3432.

Any inquiry of a general nature or relating to the status of this application

or proceeding should be directed to the receptionist whose telephone number is

(703) 308-0956.

YNBH, 9/24/02

> Olk Cheudhuri Supervising Patent Com

Tochnology Center 2800

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